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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.		
10/520,928	01/11/2005	Yoshihiro Izumi	1035-561	4954		
23117 75	590 11/28/2005		EXAM	EXAMINER		
NIXON & VANDERHYE, PC 901 NORTH GLEBE ROAD, 11TH FLOOR			KUNZER, BRIAN			
ARLINGTON, VA 22203		LOOK	ART UNIT	PAPER NUMBER		
			2814	<del></del> ,		

DATE MAILED: 11/28/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

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	Application No.	Applicant(s)	
	10/520,928	IZUMI, YOSHIHIRO	
Office Action Summary	Examiner	Art Unit	
	Brian Kunzer	2814	
The MAILING DATE of this communication Period for Reply	appears on the cover sheet w	ith the correspondence address	
A SHORTENED STATUTORY PERIOD FOR RETHE MAILING DATE OF THIS COMMUNICATION - Extensions of time may be available under the provisions of 37 CF after SIX (6) MONTHS from the mailing date of this communication. If the period for reply specified above is less than thirty (30) days, If NO period for reply is specified above, the maximum statutory period for reply within the set or extended period for reply will, by some Any reply received by the Office later than three months after the rearned patent term adjustment. See 37 CFR 1.704(b).	ON. R 1.136(a). In no event, however, may a n. a reply within the statutory minimum of the eriod will apply and will expire SIX (6) MO statute, cause the application to become A	reply be timely filed  rty (30) days will be considered timely.  NTHS from the mailing date of this communication.  BANDONED (35 U.S.C. § 133).	
Status			
Responsive to communication(s) filed on 2     This action is <b>FINAL</b> . 2b)     Since this application is in condition for all closed in accordance with the practice unc	This action is non-final.  Dwance except for formal ma	• •	
Disposition of Claims			
4) Claim(s) 1-21 is/are pending in the applica 4a) Of the above claim(s) 9-13 is/are withd 5) Claim(s) is/are allowed. 6) Claim(s) 1-8 and 14-21 is/are rejected. 7) Claim(s) is/are objected to. 8) Claim(s) are subject to restriction and Application Papers  9) The specification is objected to by the Example 10) The drawing(s) filed on is/are: a) Applicant may not request that any objection to Replacement drawing sheet(s) including the co	rawn from consideration.  nd/or election requirement.  miner.  accepted or b) □ objected to the drawing(s) be held in abeya	nce. See 37 CFR 1.85(a). g(s) is objected to. See 37 CFR 1.121(d)	).
Priority under 35 U.S.C. § 119			
12) Acknowledgment is made of a claim for formal All b) Some * c) None of:  1. Certified copies of the priority documed 2. Certified copies of the priority documed 3. Copies of the certified copies of the application from the International But * See the attached detailed Office action for a second sec	nents have been received. nents have been received in a priority documents have been ureau (PCT Rule 17.2(a)).	Application No n received in this National Stage	
Attachment(s)			
<ol> <li>Notice of References Cited (PTO-892)</li> <li>Notice of Draftsperson's Patent Drawing Review (PTO-9483)</li> <li>Information Disclosure Statement(s) (PTO-1449 or PTO/SI Paper No(s)/Mail Date 1/11/05.</li> </ol>	B) Paper No	Summary (PTO-413) (s)/Mail Date Informal Patent Application (PTO-152)	

#### **DETAILED ACTION**

#### Election/Restrictions

Applicant's election without traverse of claims 1-8 and 14-21 in the reply filed on October 24, 2005 is acknowledged.

Claims 9-13 have been withdrawn by applicant and therefore their status in the amended claims should reflect that and should not state "(original)" or "(previously presented)" in front of them. Appropriate correction is required.

## Claim Objections

- 1. Claim 3 is objected to because of the following informalities: the claim recites the limitation of "a thickness of the first insulating layer is thinner in an area positioned on or above the pixel capacitor section than in other area." It would be grammatically correct if applicant stated, "than in other <u>areas</u>" or "than in <u>another</u> area." Appropriate correction is required.
- 2. Claims 7, 16, and 20 are objected to because of the following informalities: these claims recite the limitation of a conversion layer that "converts a radiant ray into light." As best understood by examiner, applicant has meant to say "converts a non-visible radiant ray [i.e. x-ray or uv-ray] into visible light" as is detailed in the specification. To say that a radiant ray (of light?) is converted into light renders these claims indefinite (or extremely broad) since the two concepts are one in the same. Appropriate correction is required.

### Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 3. Claims 1, 2, 5, 6, 8, 14, 15, and 17 are rejected under 35 U.S.C. 102(e) as being anticipated by Choo (US Patent No. 6,617,584).

With respect to claim 1, Choo teaches, from fig. 7 (column 6 lines 1-26), a photoelectric conversion device, comprising: a first insulating layer (68 and 72), formed so as to cover a photoelectric conversion element (formed from 58, 64, 56, and 60) and a connection electrode (90) that are formed on a substrate (51), where the first insulating layer (68 and 72) has an opening portion (78a) extending to the connection electrode (90); and a conductive layer (80, mislabeled on fig. 7, see fig. 9G) formed on the first insulating layer (68 and 72), wherein the conductive layer (80) is formed so as to be connected via the opening portion (78a) to the connection electrode (90).

With respect to claim 2, Choo teaches, from fig. 7 (column 6 lines 1-26),, a photoelectric conversion device, comprising: a first insulating layer (68 and 72) formed so as to cover a photoelectric conversion element (formed from 58, 64, 56, and 60) formed on a substrate (51); and a conductive layer (80, mislabeled on fig. 7, see fig. 9G) formed on the first insulating layer (68 and 72), wherein the conductive layer (80) is formed so as to be connected to a connection

electrode (90), formed on the substrate (51), via an exposing portion (78a) provided on an end face of the first insulating layer (68 and 72 terminate at this electrode) in order to expose at least a part of the connection electrode (90).

With respect to claims 5 and 14, both claims having similar subject matter, Choo teaches, from fig. 7, the photoelectric conversion device wherein the first insulating layer (68 and 72) includes: an inorganic insulating film (68) formed so as to cover the photoelectric conversion element (formed from 58, 64, 56, and 60); and an organic insulating film (72) formed on the inorganic insulating film (68). (Also see column 7, lines 44-46 and 59.)

With respect to claims 6 and 15, both claims having similar subject matter, Choo teaches, from fig.7 (See column 6, line 4), the photoelectric conversion device further comprising a second insulating layer (82) formed on or above the conductive layer (80, mislabeled on fig. 7, see fig. 9G), which is formed on the first insulating layer (68 and 72).

With respect to claims 8 and 17, both claims having similar subject matter, Choo teaches an image scanning apparatus, comprising the photoelectric conversion device wherein the photoelectric conversion device is used as an image scanning sensor (Specifically, for use as an X-ray imager, see background of the invention and fig. 6).

4. Claims 3, 4, 18 and 21 are rejected under 35 U.S.C. 102(e) as being anticipated by Ikeda (US Patent No. 6,323,490).

With respect to claim 3, Ikeda teaches, from fig. 69 (column 38, lines 10-43), a photoelectric conversion device, comprising: a first insulating layer (4314 and 4310) formed so as to cover a photoelectric conversion element (formed from 4316, 4312, 4309, and 4304) formed on a substrate (4301) and a pixel capacitor section (formed from 4315, 4307, and 4305) connected to the photoelectric conversion element (through 4315); and a conductive layer (4311) formed on the first insulating layer (4314 and 4310), wherein a thickness of the first insulating layer (4314 and 4310) is thinner in an area positioned on or above the pixel capacitor section than in other areas.

With respect to claim 4, Ikeda teaches, from fig. 69 (column 38, lines 10-43), the photoelectric conversion device wherein: the first insulating layer (4314 and 4310) includes an insulating protective film (4310 made of a silicon nitride film, see column 38, line 32), formed so as to cover the photoelectric conversion element (formed from 4316, 4312, 4309, and 4304), which protects the photoelectric conversion element, and the first insulating layer has a relative dielectric constant which is higher in the insulating protective film (4310) than in a portion (4314 made of an organic benzocyclobutene, see column 38, line 31-32) other than the insulating protective film. (Note that silicon nitride films have higher dielectric constants than benzocyclobutene resins.)

With respect to claim 18, Ikeda teaches, from fig. 69, the photoelectric conversion device wherein the first insulating layer (4314 and 4310) includes: an inorganic insulating film (4310) formed so as to cover the photoelectric conversion element (formed from 4316, 4312, 4309, and

4304); and an organic insulating film (4314) formed on the inorganic insulating film (4310). (Also see column 38, line 31-32.)

With respect to claim 21, Ikeda teaches an image scanning apparatus, comprising the photoelectric conversion device wherein the photoelectric conversion device is used as an image scanning sensor (Specifically, for use as an X-ray imager, see background of the invention and fig. 73).

## Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

- (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 5. Claims 7, 16 and 20 are rejected under 35 U.S.C. 103(a) as being unpatentable over Choo (US Patent No. 6,617,584) and Ikeda (US Patent No. 6,323,490) as applied to claims 1, 2, and 3 above, and further in view of Hamamoto (US Patent No. 6,800,836).

With respect to claims 7, 16, and 20 both claims having similar subject matter, as best understood by examiner, Choo and Ikeda do not specifically teach the photoelectric conversion device further comprising a conversion layer, which is formed on or above the conductive layer formed on the first insulating layer, which converts non-visible light into visible light. Although, Ikeda does teach in fig. 15, a conversion layer (202) that converts X-rays into charges. Note that

it is inherent for a photoelectric conversion device to operate with some sort of conversion layer when dealing with high-energy (ultraviolet, x-ray, gamma) light imaging.

However, Hamamoto, drawn to X-ray image processing systems, teaches, from fig. 4, a conversion layer (3, a scintillator) placed on a photoelectric conversion device that converts incoming X-rays into visible light.

Therefore, it would have been obvious to one of ordinary skill in the art, at the time of invention, to have the devices of Choo or Ikeda utilizing the conversion (scintillator) layer of Hamamoto because a conversion layer is required to prevent damage to the pixel cell array from high energy radiation such as X-rays or ultraviolet light.

6. Claim 19 is rejected under 35 U.S.C. 103(a) as being unpatentable over Ikeda-490 as applied to claim 3 above, and further in view of Choo-584.

Ikeda teaches the device of claim 3 as stated above.

Ikeda does not teach that there is a second insulating layer on the conductive layer.

However, Choo teaches, from fig. 7 (See column 6, line 4), a photoelectric conversion device further comprising a second insulating layer (82) formed on or above the conductive layer (80, mislabeled on fig. 7, see fig. 9G), which is formed on the first insulating layer (68 and 72).

Therefore, it would have been obvious to one of ordinary skill in the art, at the time of invention, to make the device of Ikeda utilizing the second insulating layer of Choo because the insulating layer functions to isolate added conductive layers and also serves as a protective coating to ensure electrical connections against environmental harm in further production steps (cleaning, etching, etc.).

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Brian Kunzer whose telephone number is (571) 272-5054. The

examiner can normally be reached on Monday-Friday 8:00-4:30 EST.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Wael Fahmy can be reached on (571) 272-1705. The fax phone number for the

organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent

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system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR

system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

BK

11/16/05

HOAI PHAM PRIMARY EXAMINER